Docket No.: 51876P355

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:

YOUNG-JIN YOON

Application No.:

Filed:

For: Semiconductor Memory Device For

Reducing Data Accessing Time

Art Group:

Examiner:

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

Eric S. Hyman, Reg. No. 30,139

Date: 7/15/01

12400 Wilshire Blvd., 7th Floor Los Angeles, California 90025 (310) 207-3800 Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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First Named Inventor	Young-Jin Yoon	_			
Art Unit		_			
Examiner Name					
Attorney Docket Number	51876P355				

			U.S. PATE	ENT DOCUMENTS		
Examiner Cite Document Number No.1 Number - Kind Code² (if know		Document Number Number - Kind Code ² (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
		US-5544124	08-06-1999	Zagar et al.		
1000		US-6288947	09-11-2001	Kim et al.		
		US-2003/0058696	03-27-2003	Han et al.		
		US-6243302	06-05-2001	Yoon et al.		
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	FOREIGN PATENT DOCUMENTS								
	Cite	Foreign Patent Document			Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	,Te			
	No.1	Country Code ³ - Number ⁴ - Kind Code ⁵ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document					
		2001-165453	05-31-2001	Hynix Semiconductor					
		2000-193821	06-28-2000	Hyundai Electronics Ind. Co. Ltd.					
7		04-239605	09-08-1992	Fujitsu Ltd.					
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Examiner		,,,	Date	
Signature			Considered	

*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English tanguage Translation is attached.

Based on PTO/SB/08A (05-03) as modified by Blakely, Solokoff, Taylor & Zafman (wtr) 05/02/2003.

Send To: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450

Information Disclosure Statement

New U.S. Patent Application for SEMICONDUCTOR MEMORY DEVICE FOR REDUCING DATA ACCESSING TIME Our Ref. No.: P03H1063/US/wy

Reference No.:

- (1) US Patent No. 5,544,124
- (2) US Patent No. 6,288,947
- (3) US Publication No. 2003/0058696 A1
- (4) US Patent No. 6,243,302
- (5) JP Laid-Open No. 2002-56677
- (6) JP Laid-Open No. 2001-35154
- (7) JP Laid-Open No. 06-88862